

HEXFRED® Ultrafast Diodes, 30 A (Single Phase Bridge MTP Power Modules)



| PRIMARY CHARACTERISTICS | | | | |
|------------------------------------|---------------------|--|--|--|
| V_{R} | 1200 V | | | |
| V_F (typical) at $I_F = 30 A$ | 2.46 V | | | |
| I _O at 88 °C | 30 A | | | |
| Q _{rr} (typical) | 720 nC | | | |
| I _{RRM} (typical) | 12 A | | | |
| t _{rr} (typical) | 121 ns | | | |
| dl _{(rec)M} /dt (typical) | 300 A/μs | | | |
| Package | MTP | | | |
| Circuit configuration | Single phase bridge | | | |

FEATURES

- Low profile package
- Low t_{rr} and Q_{rr}
- Soft reverse recovery
- Direct mounting to heatsink
- Round pin with PCB solderable terminals
- UL approved file E78996
- Low junction to case thermal resistance
- 3500 V_{RMS} insulation voltage
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



A range of extremely compact single-phase rectifier bridges offering efficient and reliable operation.

The low profile package has been specifically conceived to maximize space saving and optimize the electrical layout of the application specific power supplies.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|------------------|---|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Cathode to anode voltage | V_{R} | | 1200 | V |
| Continuous forward current per diode | I _F | T _C = 88 °C | 30 | |
| Single pulse forward current per diode | I _{FSM} | 10 ms sine or 6 ms rectangular pulse, T_J = 25 °C | 300 | Α |
| Maximum repetitive forward current per diode | I _{FRM} | | 200 | |
| Maximum power dissipation per diode | P_D | T _C = 88 °C | 85 | W |
| Operating junction temperature range | T_J | | -40 to +150 | °C |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | | | |
|--|----------------|--|------|------|------|-------|--|--|---|------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | | |
| Cathode to anode breakdown voltage | V_{BR} | I _R = 100 μA | 1200 | 1 | - | V | | | | | |
| | V _F | I _F = 30 A | - | 2.46 | 3.34 | | | | | | |
| Forward voltage | | I _F = 60 A | - | 3.11 | 4.45 | V | | | | | |
| Forward voltage | | I _F = 30 A, T _J = 125 °C | - | 2.32 | 2.96 | V | | | | | |
| | | | | | | | | I _F = 60 A, T _J = 125 °C | - | 3.07 | 3.96 |
| Reverse leakage current | I _R | V _R = 1200 V | - | 2.8 | 50 | μA | | | | | |
| | | V _R = 1200 V, T _J = 125 °C | - | 2 | 10 | mA | | | | | |
| Junction capacitance | C _T | V _R = 200 V | - | 50 | 75 | pF | | | | | |



| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|--------------------------|-------------------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | t _{rr} | T _J = 25 °C | I _F = 30 A dI _F /dt = 200 A/µs V _R = 200 V | - | 121 | 170 | - ns |
| neverse recovery time | | T _J = 125 °C | | - | 180 | 260 | |
| Peak recovery current | I _{RR} | T _J = 25 °C | | - | 12 | 16 | А |
| Peak recovery current | | T _J = 125 °C | | - | 17 | 24 | |
| Reverse recovery charge | Q _{rr} | T _J = 25 °C | | - | 720 | 1350 | nC |
| neverse recovery charge | | T _J = 125 °C | | - | 1540 | 2310 | |
| Deals yets of fell of vaccions as weart divine t | dl /dt | T _J = 25 °C | | = | 300 | - | Δ/ |
| Peak rate of fall of recovery current during t _b | dI _{(rec)M} /dt | T _J = 125 °C | | - | 265 | - | A/μs |

| INSULATION TABLE | | | | |
|------------------------|------------------|---|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| RMS insulation voltage | V _{INS} | $T_J = 25$ °C, all terminals shorted, f = 50 Hz, t = 1 s | 3500 | V |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|--|-----------------------------------|--|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -40 to +150 | °C | |
| Maximum thermal resistance, per module | R _{thJC} | DC operation | 0.18 | | |
| junction to case per junction | □thJC | DC operation | 0.73 | °C/W | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.06 | | |
| Approximate weight | | | 65 | g | |
| Mounting torque, ± 10 % to heatsink | | A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads. | 4 | Nm | |



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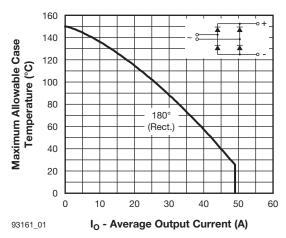


Fig. 1 - Output Current Ratings Characteristics

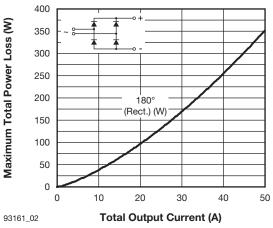


Fig. 2 - On-State Power Loss Characteristics

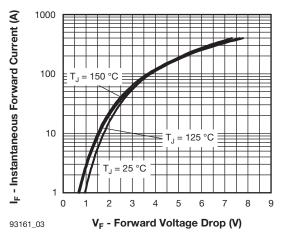


Fig. 3 - Typical Forward Voltage Drop Characteristics (Per Diode)

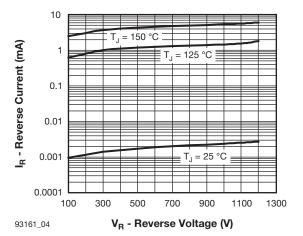


Fig. 4 - Typical Values of Reverse Current vs. Reverse Voltage (Per Diode)

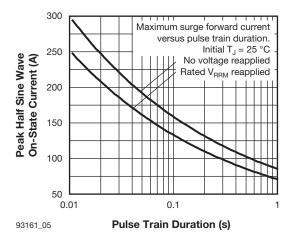


Fig. 5 - Maximum Surge Forward Current (Per Diode)

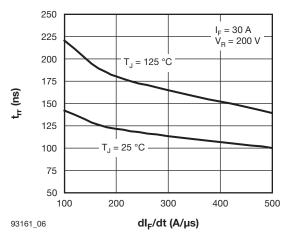
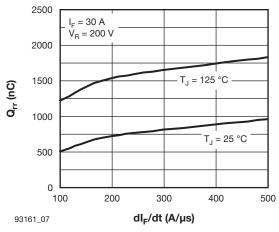


Fig. 6 - Typical Reverse Time vs. dI_F/dt (Per Diode)

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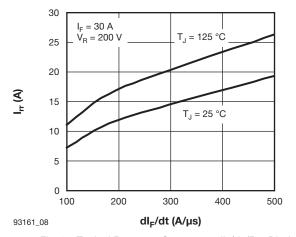


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Diode)

Fig. 8 - Typical Recovery Current vs. dl_F/dt (Per Diode)

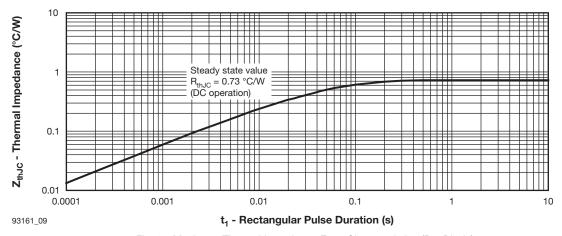
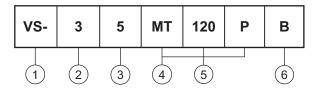


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

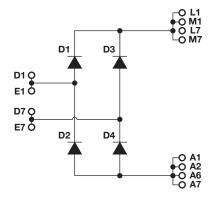
ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (3 = 30 A)
- 3 Circuit configuration code: 5 = single phase bridge
- 4 Package indicator: MT = MTP
- 5 Voltage code: code x 10 (120 = 1200 V)
- 6 Pinout code: B = round pins

CIRCUIT CONFIGURATION

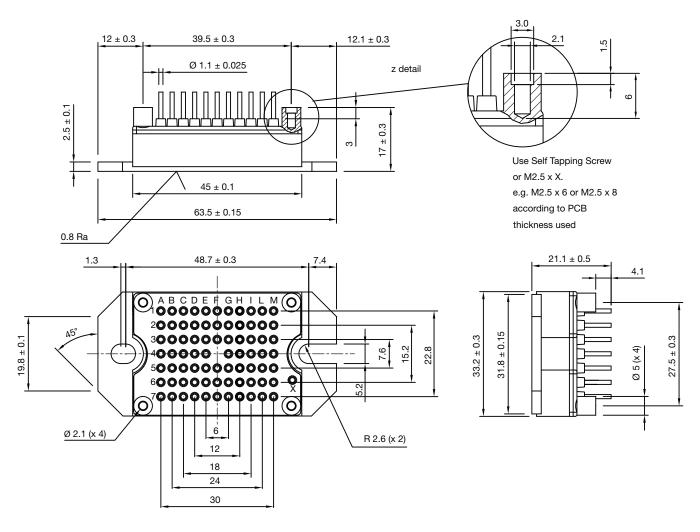


| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95383 | | |



MTP - Full Pin

DIMENSIONS in millimeters





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